# ANALOG DEVICES

# Ultracompact Precision 10 V/5 V/2.5 V/3.0 V Voltage References

# ADR01/ADR02/ADR03/ADR06

#### **FEATURES**

Ultracompact SC70-5/TSOT-5 Low temperature coefficient SOIC-8: 3 ppm/°C SC70-5/TSOT-5:9 ppm/°C Initial accuracy ± 0.1% No external capacitor required Low noise 10 µV p-p (0.1 Hz to 10 Hz) Wide operating range ADR01: 12 V to 40 V ADR02: 7 V to 40 V ADR03: 4.5 V to 40 V ADR06: 5.0 V to 40 V High output current 10 mA Wide temperature range: -40°C to +125°C ADR01/ADR02/ADR03 pin compatible to industry-standard REF01/REF02/REF03<sup>1</sup>

#### **APPLICATIONS**

Precision data acquisition systems High resolution converters Industrial process control systems Precision instruments PCMCIA cards

#### **SELECTION GUIDE**

Part Number	Output Voltage
ADR01	10.0 V
ADR02	5.0 V
ADR03	2.5 V
ADR06	3.0 V

#### Rev. F

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

#### **PIN CONFIGURATIONS**



Figure 1. 5-Lead SC70/TSOT Surface-Mount Packages



Figure 2. 8-Lead SOIC Surface-Mount Package

#### **GENERAL DESCRIPTION**

The ADR01, ADR02, ADR03, and ADR06 are precision 10 V, 5 V, 2.5 V, and 3.0 V band gap voltage references featuring high accuracy, high stability, and low power. The parts are housed in tiny SC70-5 and TSOT-5 packages, as well as the SOIC-8 versions. The SOIC-8 versions of the ADR01, ADR02, and ADR03 are drop-in replacements<sup>1</sup> to the industry-standard REF01, REF02, and REF03. The small footprint and wide operating range make the ADR0x references ideally suited for general-purpose and space-constraint applications.

With an external buffer and a simple resistor network, the TEMP terminal can be used for temperature sensing and approximation. A TRIM terminal is provided on the devices for fine adjustment of the output voltage.

The ADR01, ADR02, ADR03, and ADR06 are compact, low drift voltage references that provide an extremely stable output voltage from a wide supply voltage range. They are available in SC70-5, TSOT-5, and SOIC-8 packages with A and B grade selections. All parts are specified over the extended industrial (-40°C to +125°C) temperature range.

<sup>&</sup>lt;sup>1</sup> ADR01, ADR02, and ADR03 are component-level compatible with REF01, REF02, and REF03, respectively. No guarantees for system-level compatibility are implied. SOIC-8 versions of ADR01/ADR02/ADR03 are pin-to-pin compatible with SOIC-8 versions of REF01/REF02/REF03, respectively, with the additional temperature monitoring function.

### TABLE OF CONTENTS

Specifications	3
ADR01 Electrical Characteristics	3
ADR02 Electrical Characteristics	4
ADR03 Electrical Characteristics	5
ADR06 Electrical Characteristics	6
Dice Electrical Characteristics	7
Absolute Maximum Ratings	8
Parameter Definitions	9
Notes	9
Typical Performance Characteristics 1	0
Applications1	5

#### **REVISION HISTORY**

#### 7/04—Data Sheet Changed from Rev. E to Rev. F

Changes to	ADR02 Electrica	l Characteristics,	Table 2 4
Changes to	Ordering Guide		

#### 2/04—Data Sheet Changed from Rev. D to Rev. E

Added C grade	Universal
Changes to Outline Dimensions	
Updated Ordering Guide	

#### 8/03—Data Sheet Changed from Rev. C to Rev D

Added ADR06Universal Change to Figure 27 13

#### 6/03—Data Sheet Changed from Rev. B to Rev C

Changes to Features Section 1 Changes to General Description Section 1 Changes to Figure 2 1 Changes to Specifications Section 2 Addition of Dice Electrical Characteristics and Layout6 Changes to Absolute Maximum Ratings Section 7 Updated SOIC (R-8) Outline Dimensions 19 Changes to Ordering Guide 20

Applying the ADR01/ADR02/ADR03/ADR0615
Negative Reference
Low Cost Current Source
Precision Current Source with Adjustable Output 16
Programmable 4 to 20 mA Current Transmitter 17
Outline Dimensions
Ordering Guides 19
ADR01 Ordering Guide19
ADR02 Ordering Guide19
ADR03 Ordering Guide 20
ADR06 Ordering Guide 20

#### 2/03—Data Sheet Changed from Rev. A to Rev. B

Added ADR03	Universal
Added TSOT-5 (UJ) Package	Universal
Updated Outline Dimensions	

12/02-	-Data She	et Change	ed from Rev	. 0 to Rev. A

Changes to Features Section	1
Changes to General Description	1
Table I deleted	1
Changes to ADR01 Specifications	2
Changes to ADR02 Specifications	3
Changes to Absolute Maximum Ratings Section	4
Changes to Ordering Guide	4
Updated Outline Dimensions	

### **SPECIFICATIONS**

#### ADR01 ELECTRICAL CHARACTERISTICS

 $V_{\rm IN}$  = 12 V to 40 V,  $T_{\rm A}$  = 25°C, unless otherwise noted.

#### Table 1.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	Vo	A and C grades	9.990	10.000	10.010	V
Initial Accuracy	VOERR	A and C grades			10	mV
					0.1	%
Output Voltage	Vo	B grade	9.995	10.000	10.005	V
Initial Accuracy	VOERR	B grade			5	mV
					0.05	%
Temperature Coefficient	TCVo	A grade, SOIC-8, $-40^{\circ}C < T_A < +125^{\circ}C$		3	10	ppm/°C
		A grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade, SC70-5, -40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		B grade, SOIC-8, $-40^{\circ}C < T_{A} < +125^{\circ}C$		1	3	ppm/°C
		B grade, TSOT-5, $-40^{\circ}$ C $<$ T <sub>A</sub> $< +125^{\circ}$ C			9	ppm/°C
		B grade, SC70-5, –40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		C grade, SOIC-8, -40°C < T <sub>A</sub> < +125°C		10	40	ppm/°C
Supply Voltage Headroom	$V_{\text{IN}} - V_{\text{O}}$		2			V
Line Regulation	$\Delta V_0 / \Delta V_{IN}$	$V_{IN} = 12 \text{ V to } 40 \text{ V}, -40^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$		7	30	ppm/V
Load Regulation	$\Delta V_O / \Delta I_{LOAD}$	$I_{LOAD} = 0$ to 10 mA, $-40^{\circ}C < T_A < +125^{\circ}C$ , $V_{IN} = 15$ V		40	70	ppm/mA
Quiescent Current	lin	No load, -40°C < T <sub>A</sub> < +125°C		0.65	1	mA
Voltage Noise	e <sub>N p-p</sub>	0.1 Hz to 10 Hz		20		μV p-p
Voltage Noise Density	еN	1 kHz		510		nV/√Hz
Turn-On Settling Time	t <sub>R</sub>			4		μs
Long-Term Stability <sup>1</sup>	ΔVo	1,000 hours		50		ppm
Output Voltage Hysteresis	$\Delta V_{O_HYS}$			70		ppm
Ripple Rejection Ratio	RRR	$f_{IN} = 10 \text{ kHz}$		-75		dB
Short Circuit to GND	lsc			30		mA
Voltage Output at TEMP Pin	VTEMP			550		mV
Temperature Sensitivity	TCVTEMP			1.96		mV/°C

#### ADR02 ELECTRICAL CHARACTERISTICS

 $V_{\rm IN}$  = 7 V to 40 V,  $T_{\rm A}$  = 25°C, unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	Vo	A and C grades	4.995	5.000	5.005	V
Initial Accuracy	VOERR	A and C grades			5	mV
					0.1	%
Output Voltage	Vo	B grade	4.997	5.000	5.003	V
Initial Accuracy	VOERR	B grade			3	mV
					0.06	%
Temperature Coefficient	TCVo	A grade, SOIC-8, –40°C < T <sub>A</sub> < +125°C		3	10	ppm/°C
		A grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade, SC70-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade. SC70-5, -55℃ < TA < +125℃			30	ppm/°C
		B grade, SOIC-8, –40°C < T <sub>A</sub> < +125°C		1	3	ppm/°C
		B grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		B grade, SC70-5, –40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		C grade, SOIC-8, –40°C < T <sub>A</sub> < +125°C		10	40	ppm/°C
Supply Voltage Headroom	$V_{\text{IN}}-V_{\text{O}}$		2			V
Line Regulation	$\Delta V_0 / \Delta V_{IN}$	$V_{IN} = 7 V$ to 40 V, $-40^{\circ}C < T_A < +125^{\circ}C$		7	30	ppm/V
		$V_{IN} = 7 V \text{ to } 40 V, -55^{\circ}C < T_A < +125^{\circ}C$		7	40	ppm/V
Load Regulation	$\Delta V_{O} / \Delta I_{LOAD}$	$I_{\text{LOAD}} = 0 \text{ to } 10 \text{ mA}, -40^{\circ}\text{C} < T_{\text{A}} < +125^{\circ}\text{C}, \\ V_{\text{IN}} = 10 \text{ V}$		40	70	ppm/mA
		$I_{\text{LOAD}} = 0 \text{ to } 10 \text{ mA}, -55^{\circ}\text{C} < T_{\text{A}} < +125^{\circ}\text{C}, \\ V_{\text{IN}} = 10 \text{ V}$		45	80	ppm/mA
Quiescent Current	I <sub>IN</sub>	No load, -40°C < T <sub>A</sub> < +125°C		0.65	1	mA
Voltage Noise	e <sub>N p-p</sub>	0.1 Hz to 10 Hz		10		μV p-p
Voltage Noise Density	еN	1 kHz		230		nV/√Hz
Turn-On Settling Time	t <sub>R</sub>			4		μs
Long-Term Stability <sup>1</sup>	ΔVo	1,000 hours		50		ppm
Output Voltage Hysteresis	ΔV <sub>O_HYS</sub>			70		ppm
•		−55°C < T <sub>A</sub> < +125°C		80		ppm
Ripple Rejection Ratio	RRR	f <sub>IN</sub> = 10 kHz		-75		dB
Short Circuit to GND	lsc			30		mA
Voltage Output at TEMP Pin	VTEMP			550		mV
Temperature Sensitivity	TCV <sub>TEMP</sub>			1.96		mV/°C

#### ADR03 ELECTRICAL CHARACTERISTICS

 $V_{\rm IN}$  = 4.5 V to 40 V,  $T_{\rm A}$  = 25°C, unless otherwise noted.

Table 3.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	Vo	A and C grades	2.495	2.500	2.505	V
Initial Accuracy	VOERR	A and C grades			5	mV
					0.2	%
Output Voltage	Vo	B grades	2.4975	2.5000	2.5025	V
Initial Accuracy	VOERR	B grades			2.5	mV
					0.1	%
Temperature Coefficient	TCVo	A grade, SOIC-8, $-40^{\circ}C < T_A < +125^{\circ}C$		3	10	ppm/°C
		A grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade, SC70-5, -40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade, SC70-5, –55°C < T <sub>A</sub> < +125°C			30	ppm/°C
		B grade, SOIC-8, -40°C < T <sub>A</sub> < +125°C		1	3	ppm/°C
		B grade, TSOT-5, -40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		B grade, SC70-5, –40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		C grade, SOIC-8, -40°C < T <sub>A</sub> < +125°C		10	40	ppm/°C
Supply Voltage Headroom	$V_{\text{IN}}-V_{\text{O}}$		2			V
Line Regulation	$\Delta V_{O} / \Delta V_{IN}$	$V_{IN} = 7.5 \text{ V to } 40 \text{ V}, -40^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$		7	30	ppm/V
		$V_{IN} = 7.5 \text{ V to } 40 \text{ V}, -55^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$		7	40	ppm/V
Load Regulation	$\Delta V_{O}/\Delta I_{LOAD}$	$I_{\text{LOAD}} = 0 \text{ mA to } 10 \text{ mA}, -40^{\circ}\text{C} < T_{\text{A}} < +125^{\circ}\text{C}, \\ V_{\text{IN}} = 7.0 \text{ V}$		25	70	ppm/mA
		$I_{\text{LOAD}}$ = 0 mA to 10 mA, –55°C < $T_{\text{A}}$ < +125°C, $V_{\text{IN}}$ = 7.0 V		45	80	ppm/mA
Quiescent Current	l <sub>in</sub>	No load, -40°C < T <sub>A</sub> < +125°C		0.65	1	mA
Voltage Noise	e <sub>N p-p</sub>	0.1 Hz to 10 Hz		6		μV p-p
Voltage Noise Density	e <sub>N</sub>	1 kHz		230		nV/√Hz
Turn-On Settling Time	t <sub>R</sub>			4		μs
Long-Term Stability <sup>1</sup>	ΔVo	1,000 hours		50		ppm
Output Voltage Hysteresis	$\Delta V_{O_HYS}$			70		ppm
		–55°C < T <sub>A</sub> < +125°C		80		ppm
Ripple Rejection Ratio	RRR	$f_{IN} = 10 \text{ kHz}$		-75		dB
Short Circuit to GND	I <sub>sc</sub>			30		mA
Voltage Output at TEMP Pin	V <sub>TEMP</sub>			550		mV
Temperature Sensitivity	TCVTEMP			1.96		mV/°C

#### ADR06 ELECTRICAL CHARACTERISTICS

 $V_{\rm IN}$  = 5.0 V to 40 V,  $T_{\rm A}$  = 25°C, unless otherwise noted.

Table 4.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	Vo	A and C grades	2.994	3.000	3.006	V
Initial Accuracy	VOERR	A and C grades			6	mV
					0.2	%
Output Voltage	Vo	B grade	2.997	3.000	3.003	V
Initial Accuracy	VOERR	B grade			3	mV
					0.1	%
Temperature Coefficient	TCVo	A grade, SOIC-8, -40°C < T <sub>A</sub> < +125°C		3	10	ppm/°C
		A grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		A grade, SC70-5, –40°C < T <sub>A</sub> < +125°C			25	ppm/°C
		B grade, SOIC-8, –40°C < T <sub>A</sub> < +125°C		1	3	ppm/°C
		B grade, TSOT-5, –40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		B grade, SC70-5, −40°C < T <sub>A</sub> < +125°C			9	ppm/°C
		C grade, SOIC-8, –40°C < T <sub>A</sub> < +125°C		10	40	ppm/°C
Supply Voltage Headroom	$V_{\rm IN} - V_{\rm O}$		2			V
Line Regulation	$\Delta V_{O} / \Delta V_{IN}$	$V_{IN} = 15 \text{ V to } 40 \text{ V}, -40^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$		7	30	ppm/V
Load Regulation	$\Delta V_O / \Delta I_{LOAD}$	$I_{LOAD} = 0 \text{ to } 10 \text{ mA}, -40^{\circ}\text{C} < T_{\text{A}} < +125^{\circ}\text{C}, V_{\text{IN}} = 7.0 \text{ V}$		40	70	ppm/mA
Quiescent Current	l <sub>IN</sub>	No load, -40°C < T <sub>A</sub> < +125°C		0.65	1	mA
Voltage Noise	e <sub>N p-p</sub>	0.1 Hz to 10 Hz		10		μV p-p
Voltage Noise Density	e <sub>N</sub>	1 kHz		510		nV/√Hz
Turn-On Settling Time	t <sub>R</sub>			4		μs
Long-Term Stability <sup>1</sup>	ΔVo	1,000 hours		50		ppm
Output Voltage Hysteresis	ΔV <sub>O_HYS</sub>			70		ppm
Ripple Rejection Ratio	RRR	f <sub>IN</sub> = 10 kHz		-75		dB
Short Circuit to GND	lsc			30		mA
Voltage Output AT TEMP Pin	V <sub>TEMP</sub>			550		mV
Temperature Sensitivity	TCV <sub>TEMP</sub>			1.96		mV/°C

#### DICE ELECTRICAL CHARACTERISTICS

 $V_{\rm IN}$  = up to 40 V,  $T_{\rm A}$  = 25°C, unless otherwise noted.

#### Table 5.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage						
ADR01NBC	Vo	25°C	9.995	10.004	10.005	V
ADR02NBC	Vo	25°C	4.997	5.002	5.003	V
Temperature Coefficient	TCVo	$-40^{\circ}C < T_A < +125^{\circ}C$		10		ppm/°C
Line Regulation						
ADR01NBC	$\Delta V_{O} / \Delta V_{IN}$	$V_{IN} = 15 \text{ V} \text{ to } 40 \text{ V}$		7		ppm/V
ADR02NBC	$\Delta V_{O}/\Delta V_{IN}$	$V_{IN} = 7 V \text{ to } 40 V$		7		ppm/V
Load Regulation	$\Delta V_{O} / \Delta I_{LOAD}$	$I_{LOAD} = 0$ to 10 mA		40		ppm/mA
Quiescent Current	I <sub>IN</sub>	No load		0.65		mA
Voltage Noise	e <sub>N p-p</sub>	0.1 Hz to 10 Hz		25		μV p-p



Figure 3. Die Layout

### **ABSOLUTE MAXIMUM RATINGS**

Ratings at 25°C, unless otherwise noted.

#### Table 6.

Parameter	Rating
Supply Voltage	40 V
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	–65°C to +150°C
Operating Temperature Range	–40°C to +125°C
Junction Temperature Range: KS, UJ, and R Packages	–65°C to +150°C
Lead Temperature Range (Soldering, 60 Sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### Table 7. Thermal Resistance

Package Type	θ」a <sup>1</sup>	οισ	Unit
SC70-5 (KS-5)	376	189	°C/W
TSOT-5 (UJ-5)	230	146	°C/W
SOIC-8 (R-8)	130	43	°C/W

 ${}^{1}\theta_{JA}$  is specified for the worst-case conditions, that is,  $\theta_{JA}$  is specified for devices soldered in circuit boards for surface-mount packages.

#### **ESD CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although these products feature proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



### **PARAMETER DEFINITIONS**

#### **Temperature Coefficient**

The change of output voltage with respect to operating temperature changes normalized by the output voltage at 25°C. This parameter is expressed in ppm/°C and can be determined by the following equation:

$$TCV_{O}[ppm/°C] = \frac{V_{O}(T_{2}) - V_{O}(T_{1})}{V_{O}(25°C) \times T_{2} - T_{1}} \times 10^{6}$$

#### where:

 $V_0(25^{\circ}C) = V_0$  at  $25^{\circ}C$  $V_0(T_1) = V_0$  at Temperature 1  $V_0(T_2) = V_0$  at Temperature 2

#### Line Regulation

The change in output voltage due to a specified change in input voltage. This parameter accounts for the effects of self-heating. Line regulation is expressed in either percent per volt, partsper-million per volt, or microvolts per volt change in input voltage.

#### Load Regulation

The change in output voltage due to a specified change in load current. This parameter accounts for the effects of self-heating. Load regulation is expressed in either microvolts per milliampere, parts-per-million per milliampere, or ohms of dc output resistance.

#### Long-Term Stability

Typical shift of output voltage at 25°C on a sample of parts subjected to a test of 1,000 hours at 25°C:

$$\Delta V_O = V_O(t_0) - V_O(t_1)$$

$$\Delta V_O[ppm] = \frac{V_O(t_0) - V_O(t_1)}{V_O(t_0)} \times 10^6$$

where:

 $V_O(t_0) = V_O$  at 25°C at Time 0  $V_O(t_1) = V_O$  at 25°C after 100 hours of operation at 25°C

The majority of the shift is seen in the first 200 hours, and, as time goes by, the drift decreases significantly. So for the subsequent 1,000 hours' time points, this drift is much smaller than the first.

#### **Thermal Hysteresis**

Defined as the change of output voltage after the device is cycled through temperature from +25°C to -40°C to +125°C and back to +25°C. This is a typical value from a sample of parts put through such a cycle.

$$V_{O_{HYS}} = V_O (25^{\circ}C) - V_{O_{TC}}$$
$$V_{O_{HYS}} [ppm] = \frac{V_O (25^{\circ}C) - V_{O_{TC}}}{V_O (25^{\circ}C)} \times 10^6$$

where:

 $V_0(25^{\circ}C) = V_0 \text{ at } 25^{\circ}C$ 

 $V_{O_{TC}} = V_O$  at 25°C after temperature cycle at +25°C to -40°C to +125°C and back to +25°C

#### NOTES Input Capacitor

Input capacitors are not required on the ADR01/ADR02/ ADR03/ADR06. There is no limit for the value of the capacitor used on the input, but a 1  $\mu$ F to 10  $\mu$ F capacitor on the input improves transient response in applications where the supply suddenly changes. An additional 0.1  $\mu$ F in parallel also helps to reduce noise from the supply.

#### **Output Capacitor**

The ADR01/ADR02/ADR03/ADR06 do not require output capacitors for stability under any load condition. An output capacitor, typically 0.1  $\mu$ F, filters out any low level noise voltage and does not affect the operation of the part. On the other hand, the load transient response can be improved with an additional 1  $\mu$ F to 10  $\mu$ F output capacitor in parallel. A capacitor here acts as a source of stored energy for a sudden increase in load current. The only parameter that degrades by adding an output capacitor is the turn-on time, and it depends on the size of the capacitor chosen.

### **TYPICAL PERFORMANCE CHARACTERISTICS**



Figure 4. ADR01 Typical Output Voltage vs. Temperature



Figure 5. ADR02 Typical Output Voltage vs. Temperature



Figure 6. ADR03 Typical Output Voltage vs. Temperature



Figure 7. ADR06 Typical Output Voltage vs. Temperature



Figure 8. ADR01 Supply Current vs. Input Voltage



Figure 9. ADR02 Supply Current vs. Input Voltage

02747-F-007

02747-F-009



Figure 10. ADR03 Supply Current vs. Input Voltage







Figure 12. ADR01 Load Regulation vs. Temperature



Figure 13. ADR02 Load Regulation vs. Temperature



Figure 14. ADR03 Load Regulation vs. Temperature



Figure 15. ADR06 Load Regulation vs. Temperature

02747-F-013



Figure 16. ADR01 Line Regulation vs. Temperature



Figure 17. ADR02 Line Regulation vs. Temperature



Figure 18. ADR03 Line Regulation vs. Temperature



Figure 19. ADR06 Line Regulation vs. Temperature



10

02747-F-020

02747-F-019

Figure 20. ADR01 Minimum Input-Output Voltage Differential vs. Load Current



Figure 21. ADR02 Minimum Input-Output Voltage Differential vs. Load Current











Figure 24. ADR01 Quiescent Current vs. Load Current



Figure 25. ADR02 Typical Noise Voltage 0.1 Hz to 10 Hz



Figure 26. ADR02 Typical Noise Voltage 10 Hz to 10 KHz



Figure 27. ADR02 Line Transient Response

02747-F-026



Figure 28. ADR02 Load Transient Response

02747-F-028

02747-F-029

C <sub>LOAD</sub> = 100nF	
	V <sub>IN</sub> 5V/DIV
LOAD OFF	LOAD ON
	V <sub>OUT</sub> 100mV/DIV
	LOAD = 5mA
TIME (1.00ms	s/DIV)

Figure 29. ADR02 Load Transient Response



Figure 30. ADR02 Turn-Off Response



Figure 31. ADR02 Turn-On Response



Figure 32. ADR02 Turn-Off Response



Figure 33. ADR02 Turn-On Response

02747-F-031

02747-F-033

### **APPLICATIONS**

The ADR01/ADR02/ADR03/ADR06 are high precision, low drift 10 V, 5 V, 2.5 V, and 3.0 V voltage references available in an ultracompact footprint. The SOIC-8 version of the devices is a drop-in replacement of the REF01/REF02/ REF03 sockets with improved cost and performance.

These devices are standard band gap references. The band gap cell contains two NPN transistors (Q18 and Q19) that differ in emitter area by  $2\times$ . The difference in their V<sub>BE</sub> produces a proportional-to-absolute temperature current (PTAT) in R14, and, when combined with the V<sub>BE</sub> of Q19, produces a band gap voltage, V<sub>BG</sub>, that is almost constant in temperature. With an internal op amp and the feedback network of R5 and R6, V<sub>0</sub> is set precisely at 10 V, 5 V, 2.5 V, and 3.0 V for the ADR01, ADR02, ADR06, and ADR03, respectively. Precision laser trimming of the resistors and other proprietary circuit techniques are used to further enhance the initial accuracy, temperature curvature, and drift performance of the ADR01/ADR02/ADR03/ADR06.



Figure 34. Simplified Schematic Diagram

The PTAT voltage is made available at the TEMP pin of the ADR01/ADR02/ADR03/ADR06. It has a stable 1.96 mV/°C temperature coefficient, such that users can estimate the temperature change of the device by knowing the voltage change at the TEMP pin.

#### APPLYING THE ADR01/ADR02/ADR03/ADR06

The devices can be used without any external components to achieve the specified performance. Because of the internal op amp amplifying the band gap cell to 10 V/5 V/2.5 V/3.0 V, power supply decoupling helps the transient response of the ADR01/ADR02/ADR03/ADR06. As a result, a 0.1  $\mu$ F ceramic type decoupling capacitor should be applied as close as possible

to the input and output pins of the device. An optional 1  $\mu F$  to 10  $\mu F$  bypass capacitor can also be applied at the  $V_{\rm IN}$  node to maintain the input under transient disturbance.





#### **Output Adjustment**

The ADR01/ADR02/ADR03/ADR06 trim terminal can be used to adjust the output voltage over a nominal voltage. This feature allows a system designer to trim system errors by setting the reference to a voltage other than 10 V/5 V/2.5 V/3.0 V. For finer adjustment, a series resistor of 470 k $\Omega$  can be added. With the configuration shown in Figure 36, the ADR01 can be adjusted from 9.70 V to 10.05 V, the ADR02 can be adjusted from 4.95 V to 5.02 V, the ADR06 can be adjusted from 2.8 V to 3.3 V, and the ADR03 can be adjusted from 2.3 V to 2.8 V. Adjustment of the output does not significantly affect the temperature performance of the device, provided the temperature coefficients of the resistors are relatively low.



Figure 36. Optional Trim Adjustment

#### Temperature Monitoring

As described previously, the ADR01/ADR02/ADR03/ADR06 provide a TEMP output (Pin 3) that varies linearly with temperature. This output can be used to monitor the temperature change in the system. The voltage at VTEMP is approximately 550 mV at 25°C, and the temperature coefficient is approximately 1.96 mV/°C (see Figure 37). A voltage change of 39.2 mV at the TEMP pin corresponds to a 20°C change in temperature.



Figure 37. Voltage at TEMP Pin vs. Temperature

02747-F-037

The TEMP function is provided as a convenience rather than a precise feature. Because the voltage at the TEMP node is acquired from the band gap core, current pulling from this pin has a significant effect on V<sub>OUT</sub>. Care must be taken to buffer the TEMP output with a suitable low bias current op amp, such as the AD8601, AD820, or OP1177, all of which would result in less than a 100  $\mu$ V change in  $\Delta$ V<sub>OUT</sub> (see Figure 38). Without buffering, even tens of microamps drawn from the TEMP pin can cause V<sub>OUT</sub> to fall out of specification.



#### **NEGATIVE REFERENCE**

Without using any matching resistors, a negative reference can be configured as shown in Figure 39. For the ADR01, the voltage difference between  $V_{OUT}$  and GND is 10 V. Because  $V_{OUT}$  is at virtual ground, U2 closes the loop by forcing the GND pin to be the negative reference node. U2 should be a precision op amp with a low offset voltage characteristic.



Figure 39. Negative Reference

#### LOW COST CURRENT SOURCE

Unlike most references, the ADR01/ADR02/ADR03/ADR06 employ an NPN Darlington in which the quiescent current remains constant with respect to the load current, as shown in Figure 24. As a result, a current source can be configured as shown in Figure 40 where  $I_{SET} = (V_{OUT} - V_L)/R_{SET}$ . IL is simply the sum of  $I_{SET}$  and  $I_Q$ . Although simple,  $I_Q$  varies typically from 0.55 to 0.65 mA, limiting this circuit to general-purpose applications.



Figure 40. Low Cost Current Source

# PRECISION CURRENT SOURCE WITH ADJUSTABLE OUTPUT

A precision current source, on the other hand, can be implemented with the circuit shown in Figure 41. By adding a mechanical or digital potentiometer, this circuit becomes an adjustable current source. If a digital potentiometer is used, the load current is simply the voltage across terminals B to W of the digital potentiometer divided by R<sub>SET</sub>.

$$I_L = \frac{V_{REF} \times D}{R_{SET}} \tag{1}$$

where *D* is the decimal equivalent of the digital potentiometer input code.



Figure 41. Programmable 0 to 5 mA Current Source

To optimize the resolution of this circuit, dual-supply op amps should be used because the ground potential of ADR02 can swing from -5 V at zero scale to V<sub>L</sub> at full scale of the potentiometer setting.

# PROGRAMMABLE 4 TO 20 mA CURRENT TRANSMITTER

Because of their precision, adequate current handling, and small footprint, the devices are suitable as the reference sources for many high performance converter circuits. One of these applications is the multichannel 16-bit 4 to 20 mA current transmitter in the industrial control market (see Figure 42). This circuit employs a Howland current pump at the output, which yields better efficiency, a lower component count, and a higher voltage compliance than the conventional design with op amps and MOSFETs. In this circuit, if the resistors are matched such that R1 = R1', R2 = R2', R3 = R3', the load current is

$$I_{L} = \frac{(R2 + R3)/R1}{R3'} \times \frac{V_{REF} \times D}{2^{N}}$$
(2)

where *D* is similarly the decimal equivalent of the DAC input code and *N* is the number of bits of the DAC.

According to Equation 2, R3' can be used to set the sensitivity. R3' can be made as small as necessary to achieve the current needed within U4 output current driving capability. On the other hand, other resistors can be kept high to conserve power.



Figure 42. Programmable 4 to 20 mA Transmitter

In this circuit, the AD8512 is capable of delivering 20 mA of current, and the voltage compliance approaches 15 V.

The Howland current pump yields a potentially infinite output impedance, which is highly desirable, but resistance matching is critical in this application. The output impedance can be determined using Equation 3. As can be seen by this equation, if the resistors are perfectly matched,  $Z_0$  is infinite. On the other hand, if they are not matched,  $Z_0$  is either positive or negative. If the

latter is true, oscillation may occur. For this reason, a capacitor, C1, in the range of 1 pF to 10 pF should be connected between VP and the output terminal of U4, to filter any oscillation.

$$Z_O = \frac{V_t}{I_t} = \frac{RI'}{\left(\frac{RI'R2}{RIR2'} - 1\right)}$$
(3)

In this circuit, an ADR01 provides the stable 10.000 V reference for the AD5544 quad 16-bit DAC. The resolution of the adjustable current is 0.3  $\mu$ A/step, and the total worst-case INL error is merely 4 LSB. Such error is equivalent to 1.2  $\mu$ A or a 0.006% system error, which is well below most systems' requirements. The result is shown in Figure 43 with measurement taken at 25°C and 70°C; total system error of 4 LSB at both 25°C and 70°C.



Figure 43. Result of Programmable 4 to 20 mA Current Transmitter

#### **Precision Boosted Output Regulator**

A precision voltage output with boosted current capability can be realized with the circuit shown in Figure 44. In this circuit, U2 forces  $V_0$  to be equal to  $V_{REF}$  by regulating the turn-on of N1, thereby making the load current furnished by  $V_{IN}$ . In this configuration, a 50 mA load is achievable at  $V_{IN}$  of 15 V. Moderate heat is generated on the MOSFET, and higher current can be achieved with a replacement of a larger device. In addition, for a heavy capacitive load with a fast edging input signal, a buffer should be added at the output to enhance the transient response.



Figure 44. Precision Boosted Output Regulator

### **OUTLINE DIMENSIONS**



COMPLIANT TO JEDEC STANDARDS MO-203AA

Figure 45. 5-Lead Thin Shrink Small Outline Transistor Package [SC70] (KS-5) Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-193AB





COMPLIANT TO JEDEC STANDARDS MS-012AA CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 47. 8-Lead Standard Small Outline Package [SOIC] Narrow Body (R-8) Dimensions shown in millimeters and (inches)

### **ORDERING GUIDES**

#### **ADR01 ORDERING GUIDE**

	Output Voltage	Initial Accura	асу	Temperature Coefficient	Package	Package	Тор	Number of Parts per	Temperature
Model	<b>V</b> o ( <b>V</b> )	(mV)	(%)	(ppm/°C)	Description	Option	Mark <sup>1</sup>	Reel/Tray	Range (°C)
ADR01AR	10	10	0.1	10	SOIC-8	R-8	ADR01	98	-40 to +125
ADR01AR-REEL7	10	10	0.1	10	SOIC-8	R-8	ADR01	1,000	-40 to +125
ADR01BR	10	5	0.05	3	SOIC-8	R-8	ADR01	98	-40 to +125
ADR01BR-REEL7	10	5	0.05	3	SOIC-8	R-8	ADR01	1,000	-40 to +125
ADR01AUJ-REEL7	10	10	0.1	25	TSOT-23-5	UJ-5	R8A	3,000	-40 to +125
ADR01AUJ-R2	10	10	0.1	25	TSOT-23-5	UJ-5	R8A	250	-40 to +125
ADR01BUJ-REEL7	10	5	0.05	9	TSOT-23-5	UJ-5	R8B	3,000	-40 to +125
ADR01BUJ-R2	10	5	0.05	9	TSOT-23-5	UJ-5	R8B	250	-40 to +125
ADR01AKS-REEL7	10	10	0.1	25	SC70	KS-5	R8A	3,000	-40 to +125
ADR01AKS-R2	10	10	0.1	25	SC70	KS-5	R8A	250	-40 to +125
ADR01BKS-REEL7	10	5	0.05	9	SC70	KS-5	R8B	3,000	-40 to +125
ADR01BKS-R2	10	5	0.05	9	SC70	KS-5	R8B	250	-40 to +125
ADR01CRZ <sup>2</sup>	10	10	0.1	40	SOIC-8	R-8	ADR01	98	-40 to +125
ADR01CRZ-REEL <sup>2</sup>	10	10	0.1	40	SOIC-8	R-8	ADR01	2,500	-40 to +125
ARR01NBC	10	5	0.05	10 (Typ)	Dice			360	

<sup>1</sup> First line shows part number ADR01; second line shows A or B for the grade, with the YYMM date code; third line shows the lot number. <sup>2</sup> Z = Pb-free part.

#### **ADR02 ORDERING GUIDE**

	Output	Initial		Temperature				Number of	
	Voltage	Accura	асу	Coefficient	Package	Package	Тор	Parts per	Temperature
Model	<b>V</b> <sub>o</sub> ( <b>V</b> )	(mV)	(%)	(ppm/°C)	Description	Option	Mark <sup>1</sup>	Reel/Tray	Range (°C)
ADR02AR	5	5	0.1	10	SOIC-8	R-8	ADR02	98	-40 to +125
ADR02AR-REEL	5	5	0.1	10	SOIC-8	R-8	ADR02	1,000	-40 to +125
ADR02AR-REEL7	5	5	0.1	10	SOIC-8	R-8	ADR02	1,000	-40 to +125
ADR02ARZ <sup>2</sup>	5	5	0.1	10	SOIC-8	R-8	ADR02	98	-40 to +125
ADR02ARZ-REEL <sup>2</sup>	5	5	0.1	10	SOIC-8	R-8	ADR02	2,500	-40 to +125
ADR02BR	5	3	0.06	3	SOIC-8	R-8	ADR02	98	-40 to +125
ADR02BR-REEL7	5	3	0.06	3	SOIC-8	R-8	ADR02	1,000	-40 to +125
ADR02AUJ-REEL7	5	5	0.1	25	TSOT-23-5	UJ-5	R9A	3,000	-40 to +125
ADR02AUJ-R2	5	5	0.1	25	TSOT-23-5	UJ-5	R9A	250	-40 to +125
ADR02BUJ-REEL7	5	3	0.06	9	TSOT-23-5	UJ-5	R9B	3,000	-40 to +125
ADR02BUJ-R2	5	3	0.06	9	TSOT-23-5	UJ-5	R9B	250	-40 to +125
ADR02AKS-REEL7	5	5	0.1	25	SC70	KS-5	R9A	3,000	-40 to +125
ADR02AKS-R2	5	5	0.1	25	SC70	KS-5	R9A	250	-40 to +125
ADR02BKS-REEL7	5	3	0.06	9	SC70	KS-5	R9B	3,000	-40 to +125
ADR02BKS-R2	5	3	0.06	9	SC70	KS-5	R9B	250	-40 to +125
ADR02CRZ <sup>2</sup>	5.0	5	0.1	40	SOIC-8	R-8	ADR02	98	-40 to +125
ADR02CRZ-REEL <sup>2</sup>	5.0	5	0.1	40	SOIC-8	R-8	ADR02	2500	-40 to +125
ARR02NBC	5	3	0.06	10 (Typ)	Dice			360	

<sup>1</sup> First line shows part number ADR02; second line shows A or B for the grade, with the YYMM date code; third line shows the lot number. <sup>2</sup> Z = Pb-free part.

#### **ADR03 ORDERING GUIDE**

	Output	Initial		Temperature				Number of	
	Voltage	Accura	· ·	Coefficient	Package	Package	Тор	Parts per	Temperature
Model	<b>V</b> <sub>o</sub> ( <b>V</b> )	(mV)	(%)	(ppm/°C)	Description	Option	Mark <sup>1</sup>	Reel/Tray	Range (°C)
ADR03AR	2.5	5	0.2	10	SOIC-8	R-8	ADR03	98	-40 to +125
ADR03AR-REEL7	2.5	5	0.2	10	SOIC-8	R-8	ADR03	1,000	-40 to +125
ADR03BR	2.5	2.5	0.1	3	SOIC-8	R-8	ADR03	98	-40 to +125
ADR03BR-REEL7	2.5	2.5	0.1	3	SOIC-8	R-8	ADR03	1,000	-40 to +125
ADR03AUJ-REEL7	2.5	5	0.2	25	TSOT-23-5	UJ-5	RFA	3,000	-40 to +125
ADR03AUJ-R2	2.5	5	0.2	25	TSOT-23-5	UJ-5	RFA	250	-40 to +125
ADR03BUJ-REEL7	2.5	2.5	0.1	9	TSOT-23-5	UJ-5	RFB	3,000	-40 to +125
ADR03BUJ-R2	2.5	2.5	0.1	9	TSOT-23-5	UJ-5	RFB	250	-40 to +125
ADR03AKS-REEL7	2.5	5	0.2	25	SC70	KS-5	RFA	3,000	-40 to +125
ADR03AKS-R2	2.5	5	0.2	25	SC70	KS–5	RFA	250	-40 to +125
ADR03BKS-REEL7	2.5	2.5	0.1	9	SC70	KS-5	RFB	3,000	-40 to +125
ADR03BKS-R2	2.5	2.5	0.1	9	SC70	KS–5	RFB	250	-40 to +125
ADR03BKSZ–REEL7 <sup>2</sup>	2.5	2.5	0.1	9	SC70	KS–5	RFB	3,000	-40 to +125
ADR03CRZ <sup>2</sup>	2.5	5	0.1	40	SOIC-8	R-8	ADR02	98	-40 to +125
ADR03CRZ-REEL <sup>2</sup>	2.5	5	0.1	40	SOIC-8	R-8	ADR02	2500	-40 to +125

<sup>1</sup> First line shows part number ADR03; second line shows A or B for the grade, with the YYMM date code; third line shows the lot number.

 $^{2}$  Z = Pb-free part.

#### **ADR06 ORDERING GUIDE**

	Output Voltage	Initial Accura	acy	Temperature Coefficient	Package	Package	Тор	Number of Parts per	Temperature
Model	<b>V</b> o ( <b>V</b> )	(mV)	(%)	(ppm/°C)	Description	Option	Mark <sup>1</sup>	Reel/Tray	Range (°C)
ADR06AR	3.0	6	0.2	10	SOIC-8	R-8	ADR06	98	-40 to +125
ADR06AR-REEL7	3.0	3	0.2	10	SOIC-8	R-8	ADR06	1,000	-40 to +125
ADR06BR	3.0	6	01	3	SOIC-8	R-8	ADR06	98	-40 to +125
ADR06BR-REEL7	3.0	3	0.1	3	SOIC-8	R-8	ADR06	1,000	-40 to +125
ADR06AUJ-R2	3.0	6	0.2	25	TSOT-23-5	UJ-5	RWA	250	-40 to +125
ADR06AUJ-REEL7	3.0	6	0.2	25	TSOT-23-5	UJ-5	RWA	3,000	-40 to +125
ADR06BUJ-R2	3.0	3	0.1	9	TSOT-23-5	UJ-5	RWB	250	-40 to +125
ADR06BUJ-REEL7	3.0	3	0.1	9	TSOT-23-5	UJ-5	RWB	3,000	-40 to +125
ADR06AKS-R2	3.0	6	0.2	25	SC70	KS-5	RWA	250	-40 to +125
ADR06AKS-REEL7	3.0	6	0.2	25	SC70	KS–5	RWA	3,000	-40 to +125
ADR06BKS-R2	3.0	3	0.1	9	SC70	KS-5	RWB	250	-40 to +125
ADR06BKS-REEL7	3.0	3	0.1	9	SC70	KS–5	RWB	3,000	-40 to +125
ADR06CRZ <sup>2</sup>	3.0	6	0.2	40	SOIC-8	R-8	ADR06	98	-40 to +125
ADR06CRZ-REEL <sup>2</sup>	3.0	6	0.2	40	SOIC-8	R-8	ADR06	2500	-40 to +125

<sup>1</sup> First line shows part number ADR06; second line shows A or B for the grade, with the YYMM date code; third line shows the lot number.

 $^{2}$  Z = Pb-free part.

© 2004 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners. C02747–0–7/04(F)



www.analog.com